

规格书编号

SPEC NO :

产品规格书

SPECIFICATION

CUSTOMER 客户: _____

PRODUCT 产品: _____ SAW RESONATOR _____

MODEL NO 型号: _____ HDR418M-T039 0~+150K _____

PREPARED 编制: _____ CHECKED 审核: _____

APPROVED 批准: _____ D A T E 日期: _____ 2006-5-11 _____

| | | |
|-------------------------|-------------|---------|
| 客户确认 CUSTOMER RECEIVED: | | |
| 审核 CHECKED | 批准 APPROVED | 日期 DATE |
| | | |

无锡市好达电子有限公司
Shoulder Electronics Limited

1. SCOPE

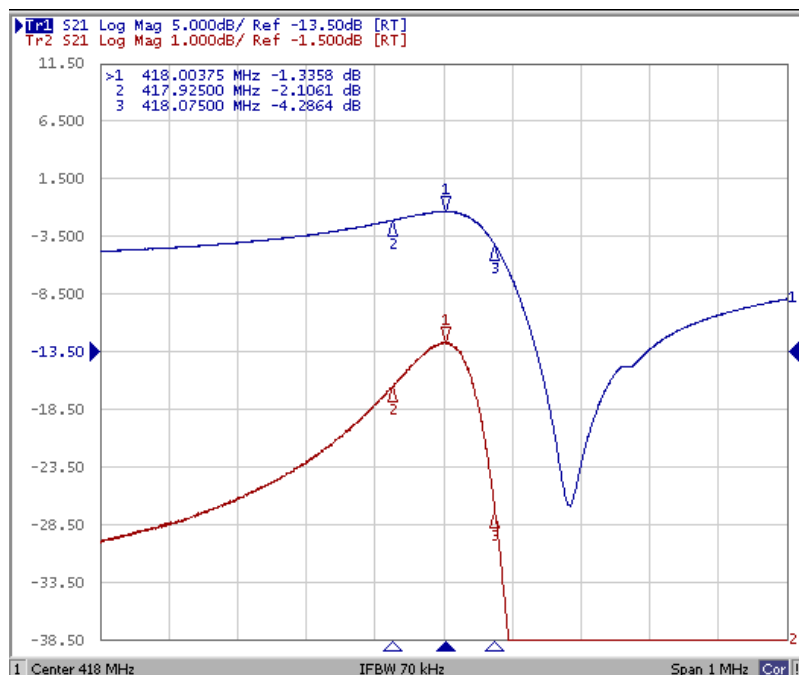
This specification shall cover the characteristics of 1-port SAW resonator with used for remote-control security.

2. ELECTRICAL SPECIFICATION

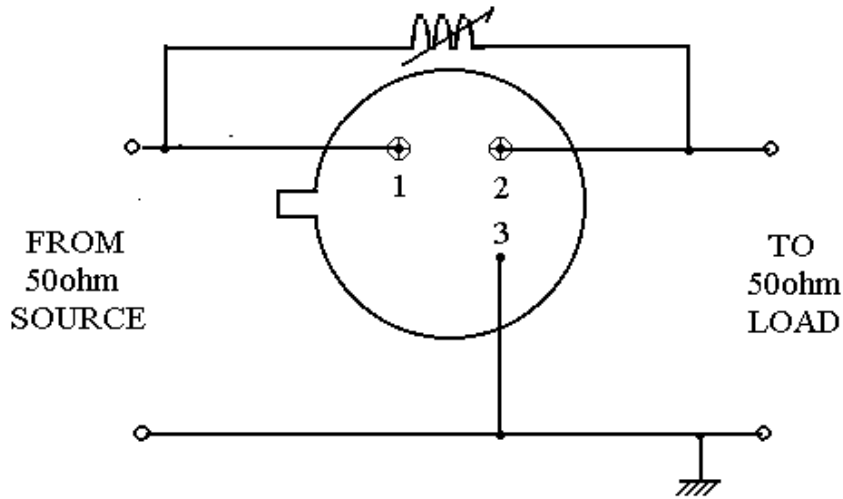
| | |
|-----------------------|----------------|
| DC Voltage VDC | 10V |
| AC Voltage Vpp | 10V50Hz/60Hz |
| Operation temperature | -40°C to +85°C |
| Storage temperature | -45°C to +85°C |
| RF Power Dissipation | 0dBm |

2.2 Electronic Characteristics

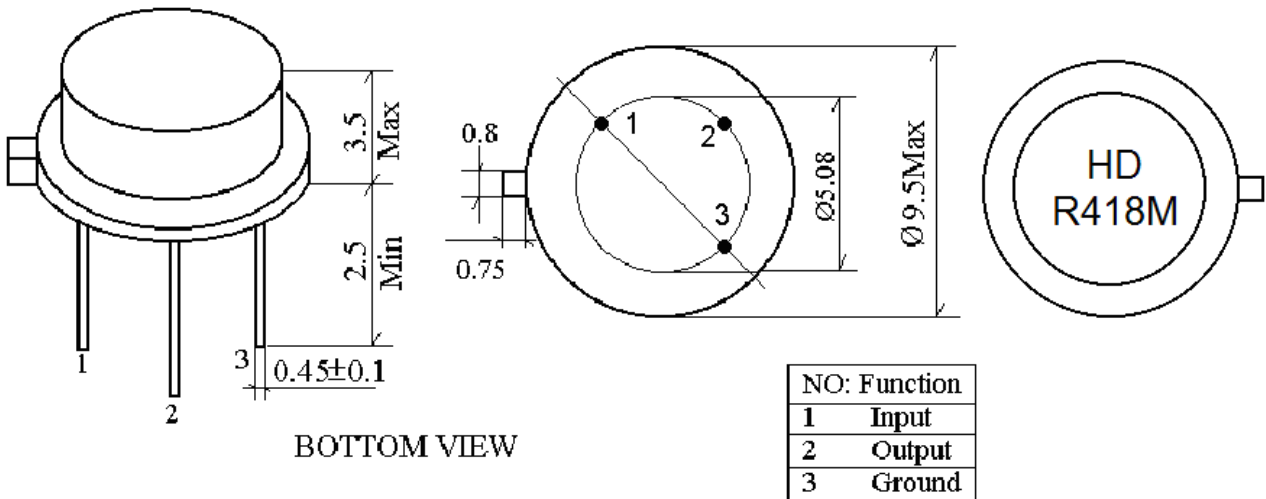
| Item | Unites | Minimum | Typical | Maximum | |
|-------------------------------|-------------------------|---------------------|---------|---------|----|
| Center Frequency | MHz | 418.000 | 418.000 | 418.150 | |
| Insertion Loss | dB | | 1.5 | 2.5 | |
| Quality Factor Unload Q | | 5000 | 10000 | | |
| 50Ω Loaded Q | | 800 | 1200 | | |
| Temperature | Turnover Temperature | °C | 10 | 25 | 40 |
| Stability | Freq.temp.Coefficient | ppm/°C ² | 0.032 | | |
| Frequency Aging | ppm/yr | | <±10 | | |
| DC. Insulation Resistance | MΩ | 1.0 | | | |
| RF Equivalent RLC Model | Motional Resistance R1 | Ω | 21 | 26 | |
| | Motional Inductance L1 | μH | 81.761 | | |
| | Motional Capacitance C1 | fF | 1.7731 | | |
| Transducer Static Capacitance | pF | | 1.9 | | |



3. TEST CIRCUIT



4. DIMENSION



5. ENVIRONMENTAL CHARACTERISTICS

5-1 High temperature exposure

Subject the device to +85°C for 16 hours. Then release the resonator into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 2.2.

5-2 Low temperature exposure

Subject the device to -40°C for 16 hours. Then release the device into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 2.2.

5-3 Temperature cycling

Subject the device to a low temperature of -40°C for 30 minutes. Following by a high temperature of +85°C for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in 2.2.

5-4 Resistance to solder heat

Dip the device terminals no closer than 1.5mm into the solder bath at $260^{\circ}\text{C} \pm 10^{\circ}\text{C}$ for 10 ± 1 sec. Then release the device into the room conditions for 4 hours. The device shall meet the specifications in 2.2.

5-5 Solderability

Subject the device terminals into the solder bath at $245^{\circ}\text{C} \pm 5^{\circ}\text{C}$ for 5s, More than 95% area of the terminals must be covered with new solder. It shall meet the specifications in 2.2.

5-6 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in 2.2.

5-7 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in 2.2.

6. REMARK

6.1 Static voltage

Static voltage between signal load & ground may cause deterioration & destruction of the component. Please avoid static voltage.

6.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

6.3 Soldering

Only leads of component may be soldered. Please avoid soldering another part of component.